| • | Application No. | Applicant(s) |
|--|---|---|
| Notice of Allowability | 10/708,746 | CHIDAMBARRAO ET AL. |
| | Examiner | Art Unit |
| | Shouxiang Hu | 2811 |
| The MAILING DATE of this communication app All claims being allowable, PROSECUTION ON THE MERITS IS herewith (or previously mailed), a Notice of Allowance (PTOL-85 NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT F of the Office or upon petition by the applicant. See 37 CFR 1.31 | S (OR REMAINS) CLOSED in to 5) or other appropriate commun RIGHTS. This application is su | his application. If not included ication will be mailed in due course. THIS |
| 1. This communication is responsive to <u>09-03-2004 Amendr</u> | <u>ment</u> . | |
| 2. The allowed claim(s) is/are 1-13. | | |
| 3. $igotimes$ The drawings filed on <u>23 March 2004</u> are accepted by the | e Examiner. | |
| 4. Acknowledgment is made of a claim for foreign priority of a) All b) Some* c) None of the: 1. Certified copies of the priority documents have 2. Certified copies of the priority documents have 3. Copies of the certified copies of the priority documents have 1. Certified copies of the priority documents have 2. Certified copies of the priority documents have 3. Copies of the certified copies of the priority documents have 1. Certified copies not received: Applicant has THREE MONTHS FROM THE "MAILING DATE noted below. Failure to timely comply will result in ABANDON THIS THREE-MONTH PERIOD IS NOT EXTENDABLE. 5. A SUBSTITUTE OATH OR DECLARATION must be subtracted by the Notice of Draftspering including changes required by the Notice of Draftspering including changes required by the Notice of Draftspering including changes required by the attached Examined Paper No./Mail Date Identifying indicia such as the application number (see 37 CFR each sheet. Replacement sheet(s) should be labeled as such in | ve been received. ve been received in Application ocuments have been received. " of this communication to file a MENT of this application. mitted. Note the attached EXAN ves reason(s) why the oath or oust be submitted. rson's Patent Drawing Review. r's Amendment / Comment or in 1.84(c)) should be written on the | No in this national stage application from the reply complying with the requirements MINER'S AMENDMENT or NOTICE OF declaration is deficient. (PTO-948) attached In the Office action of Independent of the drawings in the front (not the back) of |
| 7. DEPOSIT OF and/or INFORMATION about the department attached Examiner's comment regarding REQUIREMENT | osit of BIOLOGICAL MATER | RIAL must be submitted. Note the |
| Attachment(s) 1. ☑ Notice of References Cited (PTO-892) | 5 □ Notice of Info | ermal Patent Application (PTO-152) |
| Notice of References Cited (F10-092) Notice of Draftperson's Patent Drawing Review (PTO-948) | | · · · · · · · · · · · · · · · · · · · |
| Information Disclosure Statements (PTO-1449 or PTO/SB Paper No./Mail Date 20040323 | Paper No./M /08), 7. 🛭 Examiner's A | lail Date <u>20041124</u> . mendment/Comment |
| Examiner's Comment Regarding Requirement for Deposit of Biological Material | 9. Other . | lieusus for Allowance |
| | PR | SHOUXIANG HU IMARY EXAMINER |

Art Unit: 2811

EXAMINER'S AMENDMENT

An examiner's amendment to the record appears below. Should the changes

and/or additions be unacceptable to applicant, an amendment may be filed as provided

by 37 CFR 1.312. To ensure consideration of such an amendment, it MUST be

submitted no later than the payment of the issue fee.

Authorization for this examiner's amendment was given in telephone interviews

with Eric W. Petraske (RN: 28,459) on November 17, 2004, and with Todd Li (RN:

45,554) on November 24, 2004

The application has been amended as follows:

IN THE CLAIMS

Claims 14-20 are canceled.

In claim 1, line 14, delete the term of "outside said transistor body and".

Allowable Subject Matter

Claims 1-13 are allowed.

Reasons for Allowance

The following is an examiner's statement of reasons for allowance: Prior art does

not teach or render obvious a method for forming an N-type transistor as defined in the

above allowed claims, comprising particularly the steps of: forming a pair of temporary

Application/Control Number: 10/708,746

Art Unit: 2811

dielectric spacers on the sides of the gate electrode; removing a portion of a strained silicon layer outside the transistor body and below the pair of temporary spacers by a substantially non-directional process, which naturally forms an undercut beneath the temporally spacers, leaving a buffer portion of strained silicon in the strained silicon layer and forming a first S/D aperture outside the buffer portion; forming an electrode layer of silicon in the first S/D aperture, making mechanical and electrical contact with the transistor body and with a portion of an underlying SiGe support layer; forming transition doped areas between the transistor body and electrode areas in the electrode layer.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance."

Conclusion

The prior art made of record and not relied upon is considered pertinent to applicant's disclosure. References A-H are cited as being related to a method for forming a transistor structure involving spacers.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Shouxiang Hu whose telephone number is 571-272-1654. The examiner can normally be reached on Monday through Thursday, 7:30 AM to 6:00 PM.

Art Unit: 2811

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Eddie C. Lee can be reached on 571-272-1732. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

SH

November 24, 2004

SHOUXIANG HU PRIMARY EXAMINER